

(Γ) → $(\text{InAs}) / (\text{GaSb})$, (Γ)
 $(\approx 40\%)$ (Γ) < 4 ≥ 10
 InAs/GaSb Γ
 Σ
 Γ
 $(\Gamma, 310^\circ)$, (Γ, Σ)
 $\Gamma(\Gamma)$
 Σ

20.

10

21.

(L),

S

10

0

E

3

50%,

75%.

S = 25%,

(111)

= 25%,

S

= 50%

75%.

3,

As(In, Ga)₁/Sb(In, Ga)₂

(In, Ga)

(111)

As(In, Ga)



• u , L (L),
- u () u a